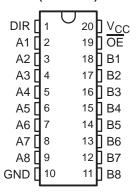
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC}, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- **Package Options Include Plastic** Small-Outline (DW, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)

description

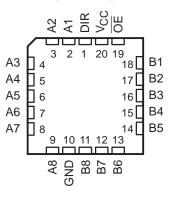
These octal bus transceivers are designed for 2-V to 5.5-V V_{CC} operation.

'LV245A devices are designed asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

SN54LV245A . . . J OR W PACKAGE SN74LV245A . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



SN54LV245A . . . FK PACKAGE (TOP VIEW)



To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LV245A is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74LV245A is characterized for operation from -40°C to 85°C.

FUNCTION TABLE

INP	UTS	OPERATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation

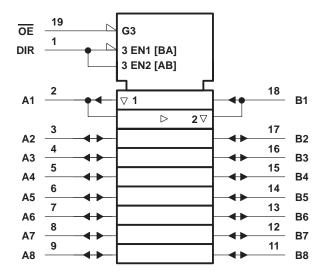


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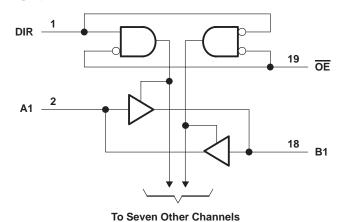


logic symbol†



 $[\]ensuremath{^{\dagger}}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I : Except I/O ports (see	Note 1)	0.5 V to 7 V
I/O ports (see Notes 1	and 2)	. -0.5 V to V _{CC} + 0.5 V
Output voltage range applied in the high or low	v state, V _O (see Notes 1 and 2)	. -0.5 V to V_{CC} + 0.5 V
Output voltage range applied in high-impedance	ce or power-off state, V _O (see Note 1)	–0.5 V to 7 V
Input clamp current, I _{IK} (V _I < 0)		–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _C	c)	±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	·	±35 mA
Continuous current through V _{CC} or GND		$\dots \dots \pm 70 \text{ mA}$
Package thermal impedance, θ _{JA} (see Note 3)): DB package	115°C/W
	DGV package	146°C/W
	DW package	97°C/W
	NS package	100°C/W
	PW package	
Storage temperature range, T _{stq}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 7 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



SN54LV245A, SN74LV245A OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCLS382C - SEPTEMBER 1997 - REVISED JUNE 1998

recommended operating conditions (see Note 4)

			SN54L\	/245A	SN74L	V245A	UNIT	
			MIN			MAX	UNII	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
V	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	V _{CC} ×0.7		$V_{CC} \times 0.7$		V	
VIH	nigri-level iriput voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	V _{CC} × 0.7		$V_{CC} \times 0.7$		V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	V _{CC} ×0.7		$V_{CC} \times 0.7$			
		V _{CC} = 2 V		0.5		0.5		
٧	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$,	V _{CC} ×0.3		$V_{CC} \times 0.3$	V	
V_{IL}	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$,	$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	l v	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$,	VCC×0.3		$V_{CC} \times 0.3$		
٧ _I	Input voltage	-	0	5.5	0	5.5	V	
.,	Output voltage	High or low state	0	Vcc	0	Vcc	V	
VO		3-state	0	5.5	0	5.5	V	
		V _{CC} = 2 V		-50		-50	μΑ	
1	High lovel cutout current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	00	-2		-2		
ЮН	High-level output current	V _{CC} = 3 V to 3.6 V	Q	-8		-8	mA	
		V _{CC} = 4.5 V to 5.5 V		-16		-16		
		V _{CC} = 2 V		50		50	μΑ	
la.	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2		
IOL	Low-level output current	V _{CC} = 3 V to 3.6 V		8		8	mA	
		V _{CC} = 4.5 V to 5.5 V		16		16		
		V _{CC} = 2.3 V to 2.7 V	0	200	0	200		
$\Delta t/\Delta v$	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V	0	100	0	100	ns/V	
		V _{CC} = 4.5 V to 5.5 V	0	20	0	20		
TA	Operating free-air temperature	-	-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DA	DAMETED	TEST CONDITIONS	T	SN	54LV24	δA	SN	74LV245	iΑ	UNIT
PARAMETER		TEST CONDITIONS	vcc	MIN	TYP	MAX	MIN	TYP	MAX	UNII
		I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.	1		V _{CC} -0.	1		
\/a		I _{OH} = -2 mA	2.3 V	2			2			V
VOH		I _{OH} = -8 mA	3 V	2.48			2.48			V
		I _{OH} = -16 mA	4.5 V	3.8			3.8			
		I _{OL} = 50 μA	2 V to 5.5 V			0.1			0.1	
\/~·		I _{OL} = 2 mA	2.3 V		1/4	0.4			0.4	V
VOL		I _{OL} = 8 mA	3 V		2/2	0.44			0.44	V
		I _{OL} = 16 mA	4.5 V		7	0.55			0.55	
l _l		V _I = V _{CC} or GND	5.5 V	1		±1			±1	μΑ
loz		$V_O = V_{CC}$ or GND	5.5 V	30		±5			±5	μΑ
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	Q		20			20	μΑ
l _{off}		V_I or $V_O = 0$ to 5.5 V	0 V			5			5	μΑ
C.	Control innuts	V. Vaaar CND	3.3 V		2.4			2.4		"r
Ci	Control inputs	V _I = V _{CC} or GND	5 V		2.4			2.4		pF
C.	A or P port	Va – Va a or CND	3.3 V		5.4		5.4			
C _{io}	A or B port	$V_O = V_{CC}$ or GND	5 V		5.4		5.4			pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	Δ = 25°C	;	SN54L\	V245A	SN74L	V245A	LINUT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t pd*	A or B	B or A			8.3	13	1	15	1	15	
t _{en} *	ŌĒ	A or B	C _L = 15 pF		11.8	19.9	1	22	1	22	ns
^t dis [*]	ŌĒ	A or B			11.8	18.1	1 ,	20	1	20	
^t pd	A or B	B or A			11.2	15.9	1	18	1	18	
t _{en}	ŌE	A or B	0 50 5		14.1	22.7	77/	26	1	26	
^t dis	ŌĒ	A or B	$C_L = 50 pF$		17.6	23.1	O 1	25	1	25	ns
t _{sk(o)} †						2	Q'			2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



[†] Skew between any two outputs of the same package switching in the same direction

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	ղ = 25°C	;	SN54L	/245A	SN74L\	/245A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
tpd*	A or B	B or A			5.9	8.4	1	10	1	10	
t _{en} *	ŌĒ	A or B	C _L = 15 pF		8.2	13.2	1	15.5	1	15.5	ns
^t dis*	ŌĒ	A or B			9.6	16.5	1 ,	19.5	1	19.5	
^t pd	A or B	B or A			7.9	11.9	1	13.5	1	13.5	
^t en	ŌĒ	A or B	0 50 5		9.9	16.7	77/	19	1	19	
^t dis	ŌĒ	A or B	C _L = 50 pF		13.9	19.8	O 1	22	1	22	ns
t _{sk(o)} †						1.5	Q			1.5	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	ղ = 25°C	;	SN54L	/245A	SN74L	/245A	UNIT
FARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
tpd*	A or B	B or A			4.3	5.5	1	6.5	1	6.5	
ten*	ŌE	A or B	C _L = 15 pF		5.7	8.5	1	10.6	1	10	ns
^t dis*	ŌE	A or B			7.8	12.8	1	14.7	1	14.2	
^t pd	A or B	B or A			5.6	7.5	1	8.5	1	8.5	
t _{en}	ŌĒ	A or B	0 50 -5		7	10.6	77/	12	1	12	
^t dis	ŌE	A or B	$C_L = 50 pF$		10.9	14.7	Q 1	16	1	16	ns
t _{sk(o)} †						1	Q.			1	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 3.3 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 5)

	PARAMETER	SN7	UNIT		
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.45		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.45		V
VOH(V)	Quiet output, minimum dynamic VOH		2.94		V
VIH(D)	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, T_A = 25°C

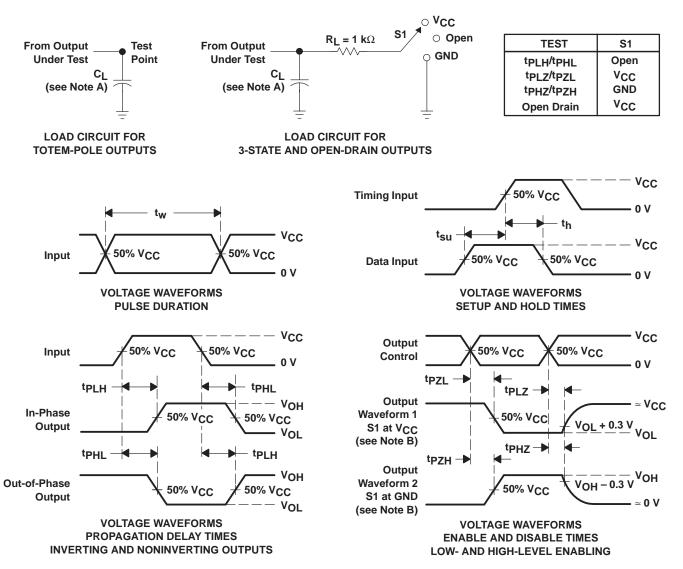
PARAMETER			TEST COI	VCC	TYP	UNIT
C _{pd} Power dissipation capacitance	Outputs enabled	$C_1 = 50 pF$	f = 10 MHz	3.3 V	20	pF
	1 Ower dissipation capacitance	Outputs enabled	$C_L = 50 \text{ pF},$	1 = 10 101112	5 V	25



[†] Skew between any two outputs of the same package switching in the same direction

[†] Skew between any two outputs of the same package switching in the same direction

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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